

#### 67 mΩ R<sub>DS(ON)</sub> 2A High-Side Load Switch in 0.85 mm x 0.85 mm FTDFN Package

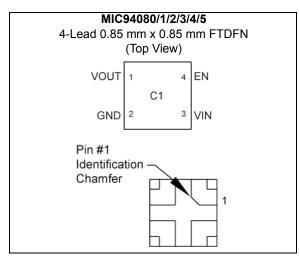
#### Features

- Space-Saving 0.85 mm x 0.85 mm 4-Lead FTDFN Package
- Input Voltage Range: 1.7V to 5.5V
- 2A Continuous Operating Current
- 67 mΩ R<sub>DS(ON)</sub>
- Internal Level Shift for CMOS/TTL Control Logic
- Ultra-Low Quiescent Current
- Micropower Shutdown Current
- Soft-Start: MIC94082/3 (800 μs), MIC94084/5 (120 μs)
- Load Discharge Circuit: MIC94081, MIC94083, MIC94085
- Ultra-Fast Turn-Off Time
- –40°C to +125°C Junction Operating Temperature

#### Applications

- Cellular Phones
- Portable Navigation Devices (PND)
- Personal Media Players (PMP)
- Ultra-Mobile PCs
- Portable Instrumentation
- Other Portable Applications
- PDAs
- GPS Modules
- Industrial and Datacom Equipment

#### Package Type



#### **General Description**

The MIC94080/1/2/3/4/5 is a family of high-side load switches designed to operate from 1.7V to 5.5V input voltage. The load switch pass element is an internal 67 m $\Omega$  R<sub>DS(ON)</sub> P-Channel MOSFET that enables the device to support up to 2A of continuous current. Additionally, the load switch supports 1.5V logic level control and shutdown features in a tiny 0.85 mm x 0.85 mm 4-lead FTDFN package.

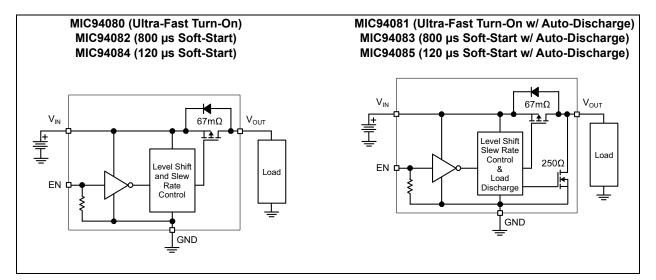
The MIC94080 and MIC94081 feature rapid turn on. The MIC94082 and MIC94083 provide a slew rate controlled soft-start turn-on of 800  $\mu$ s, while the MIC94084 and MIC94085 provide a slew rate controlled soft-start turn-on of 120  $\mu$ s. The soft-start feature is provided to prevent an in-rush current event from pulling down the input supply voltage.

The MIC94081, MIC94083, and MIC94085 feature an active load discharge circuit which switches in a  $250\Omega$  load when the switch is disabled to automatically discharge a capacitive load.

An active pull-down on the enable input keeps the MIC94080/1/2/3/4/5 in a default OFF state until the enable pin is pulled above 1.25V. Internal level shift circuitry allows low voltage logic signals to switch higher supply voltages. The enable voltage can be as high as 5.5V and is not limited by the input voltage.

The MIC94080/1/2/3/4/5 operating voltage range makes them ideal for Lithium ion and NiMH/NiCad/Alkaline battery powered systems, as well as non-battery powered applications. The devices provide low quiescent current and low shutdown current to maximize battery life.

#### **Typical Application Circuits**



### 1.0 ELECTRICAL CHARACTERISTICS

#### Absolute Maximum Ratings †

Input Voltage (V <sub>IN</sub> )	
Enable Voltage (V <sub>EN</sub> )	+6V
Continuous Drain Current (I <sub>D</sub> ) (Note 1)	
T <sub>A</sub> = +25°C	±2.0A
T <sub>A</sub> = +85°C	±1.5A
Pulsed Drain Current (I <sub>DP</sub> ) (Note 2)	±6.0A
Continuous Diode Current (I <sub>S</sub> ) (Note 3)	–50 mA
Storage Temperature (T <sub>S</sub> )	–55°C to +150°C
ESD Rating (HBM, Note 4)	3 kV

#### **Operating Ratings ††**

Input Voltage (V <sub>IN</sub> )	
Junction Temperature Range (T <sub>1</sub> )	
Package Thermal Resistance	
4-Ld FTDFN 0.85 mm x 0.85 mm (θ <sub>IA</sub> )	140°C/W
4-Ld FTDFN 0.85 mm x 0.85 mm (θ <sub>IC</sub> )	

**† Notice:** Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and functional operation of the device at those or any other conditions above those indicated in the operational sections of this specification is not intended. Exposure to maximum rating conditions for extended periods may affect device reliability.

**††** Notice: The device is not guaranteed to function outside its operating ratings.

Note 1: With thermal contact to PCB. See Thermal Considerations section.

- **2:** Pulse width <300  $\mu$ s with <2% duty cycle.
- 3: Continuous body diode current conduction (reverse conduction, i.e. V<sub>OUT</sub> to V<sub>IN</sub>) is not recommended.
- 4: Devices are ESD sensitive. Handling precautions recommended. Human body model, 1.5 k $\Omega$  in series with 100 pF.

#### **ELECTRICAL CHARACTERISTICS**

**Electrical Characteristics:**  $T_A = +25^{\circ}C$ , **bold** values indicate  $-40^{\circ}C \le T_A \le +85^{\circ}C$ , unless noted.

Parameter	Sym.	Min.	Тур.	Max.	Units	Conditions
Enable Threshold Voltage	V <sub>EN_TH</sub>	0.4	_	1.25	V	V <sub>IN</sub> = 1.7V to 4.5V, I <sub>D</sub> = –250 μA
Ouissest Current		_	0.1	1	μΑ	$V_{IN} = V_{EN} = 5.5V$ , $I_D = OPEN$ Measured on $V_{IN}$ MIC94080/1
Quiescent Current	Ι <sub>Q</sub>	_	8	15		$V_{IN} = V_{EN} = 5.5V$ , $I_D = OPEN$ Measured on $V_{IN}$ MIC94082/3/4/5
Enable Input Current	I <sub>EN</sub>	_	2.8	4	μA	$V_{IN} = V_{EN} = 5.5V$ , $I_D = OPEN$
Quiescent Current (Shutdown)	I <sub>SHUT-Q</sub>	_	0.02	1	μA	$V_{IN}$ = +5.5V, $V_{EN}$ = 0V, $I_D$ = OPEN Measured on $V_{IN}$ , Note 1
OFF State Leakage Current	I <sub>SHUT-SWITCH</sub>	_	0.02	1	μA	$V_{IN}$ = +5.5V, $V_{EN}$ = 0V, $I_D$ = SHORT Measured on $V_{IN}$ , Note 1
		_	67	115		V <sub>IN</sub> = +5.0V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V
		_	70	130		V <sub>IN</sub> = +4.5V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V
P-Channel	Р	_	80	165		V <sub>IN</sub> = +3.6V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V
Drain-to-Source ON Resistance	R <sub>DS(ON)</sub>	_	110	225	mΩ	$V_{IN}$ = +2.5V, $I_D$ = -100 mA, $V_{EN}$ = 1.5V
		_	175	350		V <sub>IN</sub> = +1.8V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V
		—	200	375		V <sub>IN</sub> = +1.7V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V
Turn-Off Resistance	R <sub>SHUTDOWN</sub>	_	250	400	Ω	V <sub>IN</sub> = +3.6V, I <sub>TEST</sub> = 1 mA, V <sub>EN</sub> = 0V MIC94081/3/5
Dynamic Electrical Ch	aracteristics					
	ton_dly	—	0.4	1.5	μs	V <sub>IN</sub> = +3.6V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V MIC94080, MIC94081
Turn-On Delay		200	600	1500		V <sub>IN</sub> = +3.6V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V MIC94082, MIC94083
		65	110	165		V <sub>IN</sub> = +3.6V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V MIC94084, MIC94085
Turn-On Rise Time	t <sub>on_rise</sub>	_	0.4	1.5	μs	V <sub>IN</sub> = +3.6V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V MIC94080, MIC94081
		400	800	1500		V <sub>IN</sub> = +3.6V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V MIC94082, MIC94083
		65	120	175		V <sub>IN</sub> = +3.6V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 1.5V MIC94084, MIC94085
Turn-Off Delay Time	t <sub>OFF_DLY</sub>	_	60	200	ns	V <sub>IN</sub> = +3.6V, I <sub>D</sub> = -100 mA, V <sub>EN</sub> = 0V
Turn-Off Fall Time	t <sub>OFF_FALL</sub>		20	100	ns	$V_{IN}$ = +3.6V, $I_{D}$ = -100 mA, $V_{EN}$ = 0V

Note 1: Measured on the MIC94080YFT.

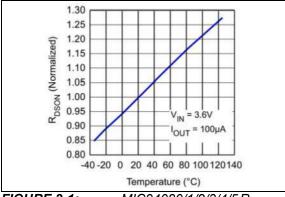
#### **TEMPERATURE SPECIFICATIONS**

Parameters	Sym.	Min.	Тур.	Max.	Units	Conditions
Temperature Ranges						
Junction Temperature Range	TJ	-40		+125	°C	—
Storage Temperature Range	Τ <sub>S</sub>	-55	_	+150	°C	—
Package Thermal Resistances						•
Thermal Resistance, 4-Ld FTDFN 0.85 mm x 0.85 mm	$\theta_{JA}$	_	140	—	°C/W	_
Thermal Resistance, 4-Ld FTDFN 0.85 mm x 0.85 mm	$\theta_{JC}$	_	85	_	°C/W	_

**Note 1:** The maximum allowable power dissipation is a function of ambient temperature, the maximum allowable junction temperature and the thermal resistance from junction to air (i.e., T<sub>A</sub>, T<sub>J</sub>, θ<sub>JA</sub>). Exceeding the maximum allowable power dissipation will cause the device operating junction temperature to exceed the maximum +125°C rating. Sustained junction temperatures above +125°C can impact the device reliability.

#### 2.0 TYPICAL PERFORMANCE CURVES

**Note:** The graphs and tables provided following this note are a statistical summary based on a limited number of samples and are provided for informational purposes only. The performance characteristics listed herein are not tested or guaranteed. In some graphs or tables, the data presented may be outside the specified operating range (e.g., outside specified power supply range) and therefore outside the warranted range.



**FIGURE 2-1:** MIC94080/1/2/3/4/5R<sub>DS(ON)</sub> Variance vs. Temperature.

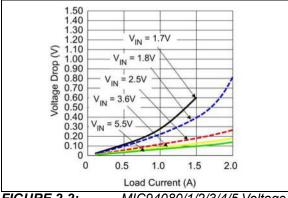


FIGURE 2-2: MIC94080/1/2/3/4/5 Voltage Drop vs. Load Current.

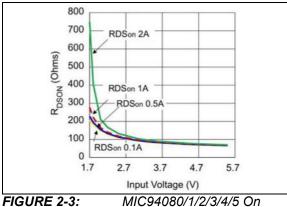


FIGURE 2-3: MIC94080/1/2/3/4/5 On Resistance vs. Input Voltage.

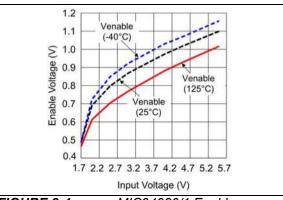


FIGURE 2-4:MIC94080/1 EnableThreshold vs. Input Voltage.

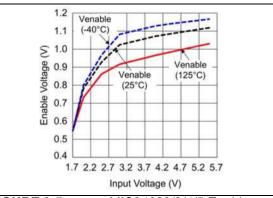
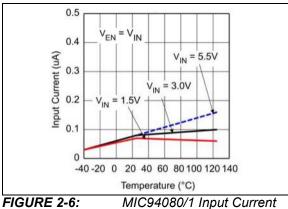
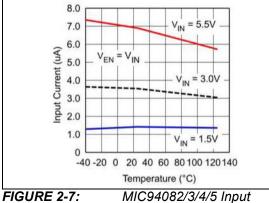


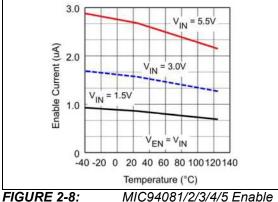
FIGURE 2-5:MIC94082/3/4/5 EnableThreshold vs. Input Voltage.



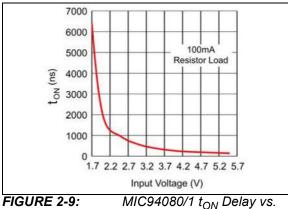
vs. Temperature.



Current vs. Temperature.



Current vs. Temperature.



Input Voltage.

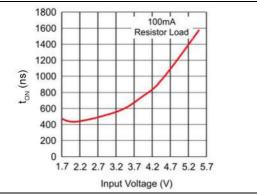


FIGURE 2-10: MIC94082/3 t<sub>ON</sub> Delay vs. Input Voltage.

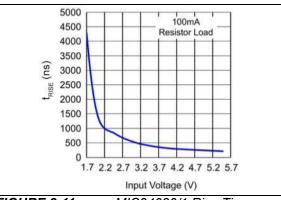


FIGURE 2-11: MIC94080/1 Rise Time vs. Input Voltage.

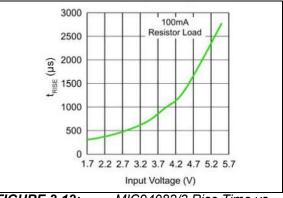
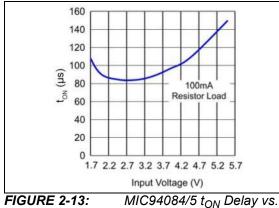
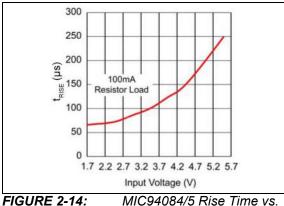


FIGURE 2-12: Input Voltage.

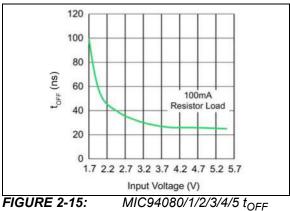
MIC94082/3 Rise Time vs.



Input Voltage.



Input Voltage.



Delay vs. Input Voltage.

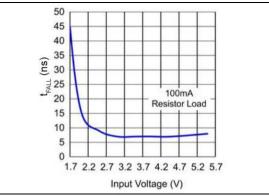
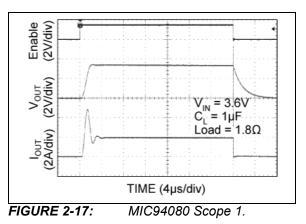
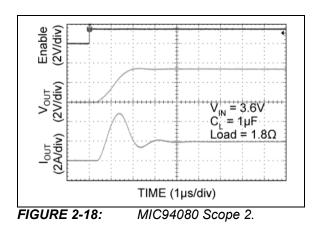
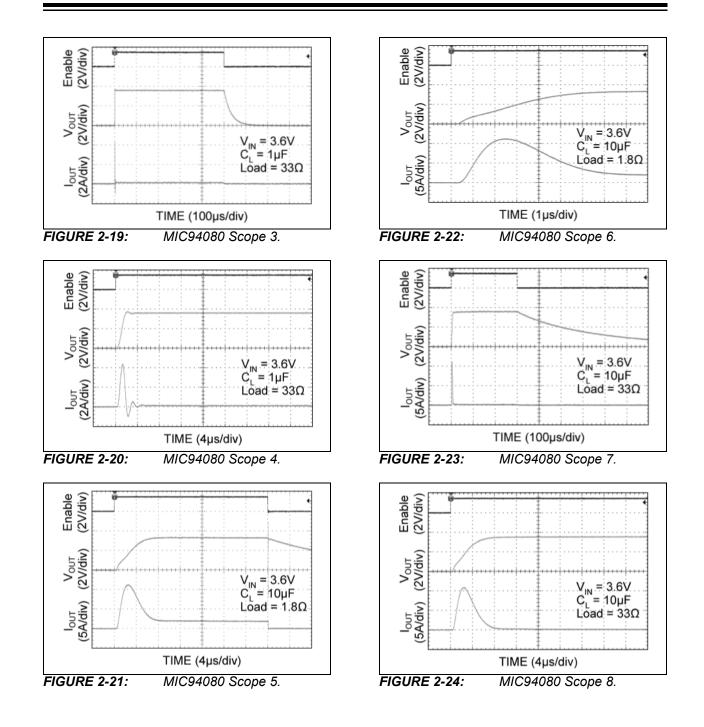
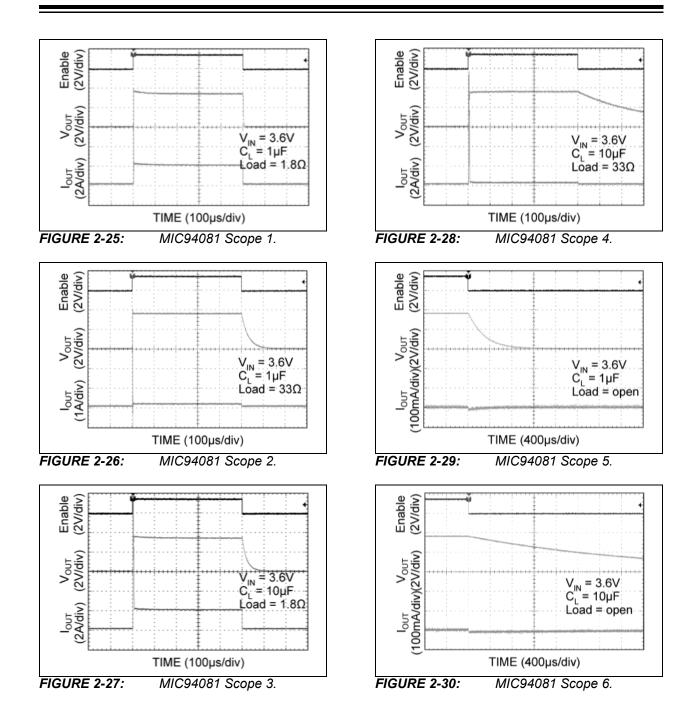


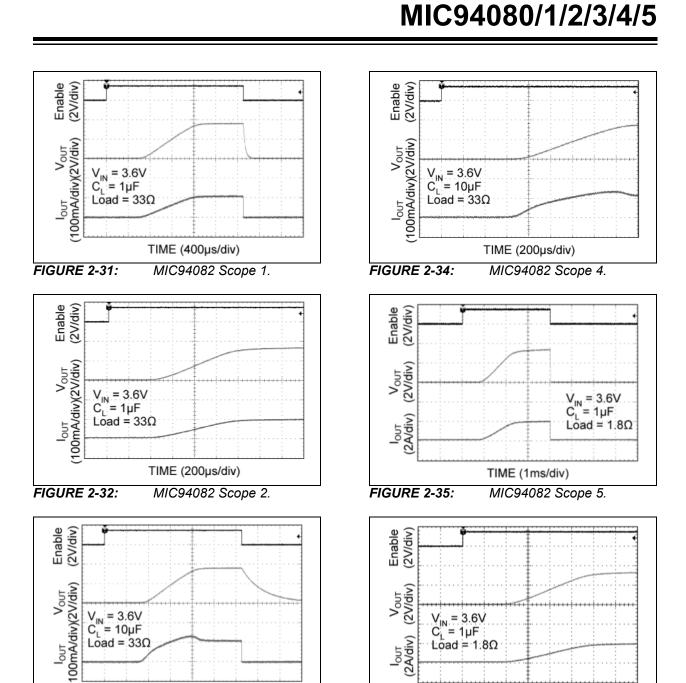
FIGURE 2-16: MIC94080/1/2/3/4/5 Fall Time vs. Input Voltage.

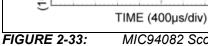








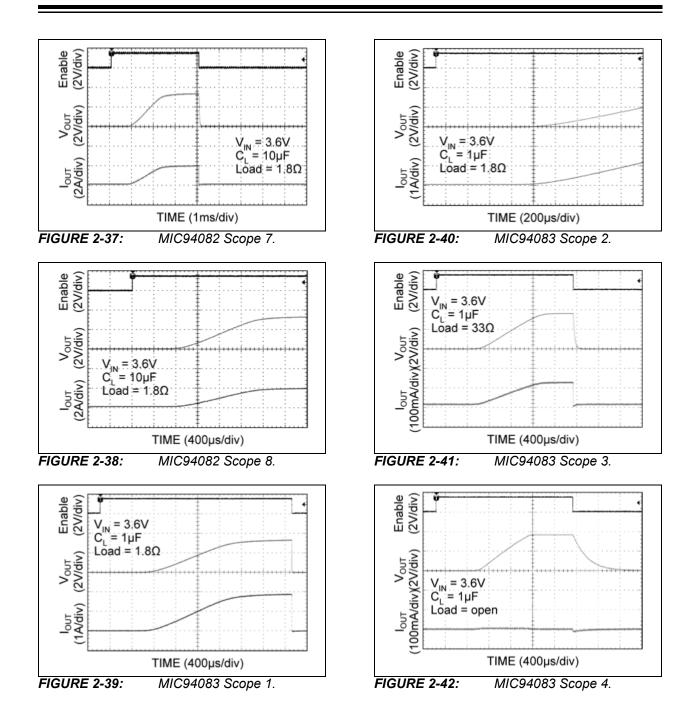


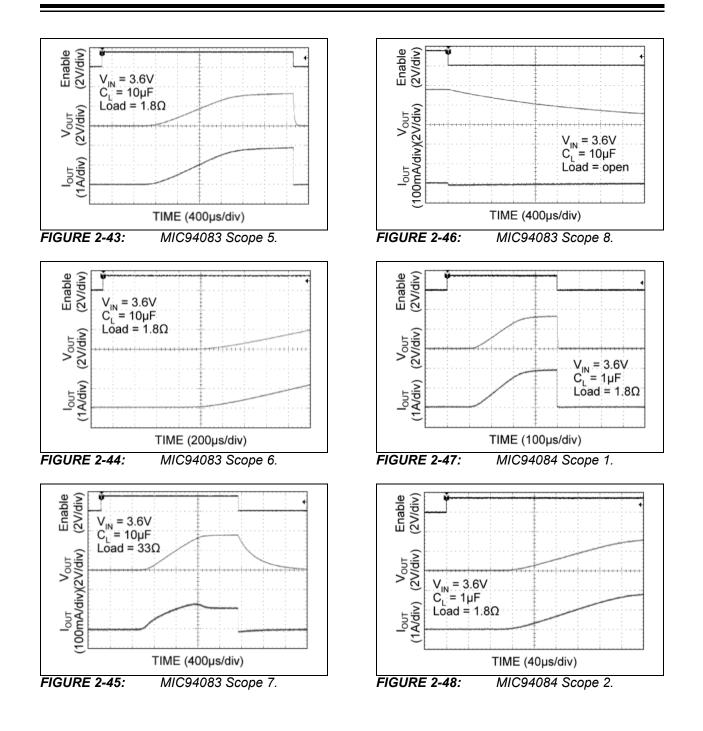


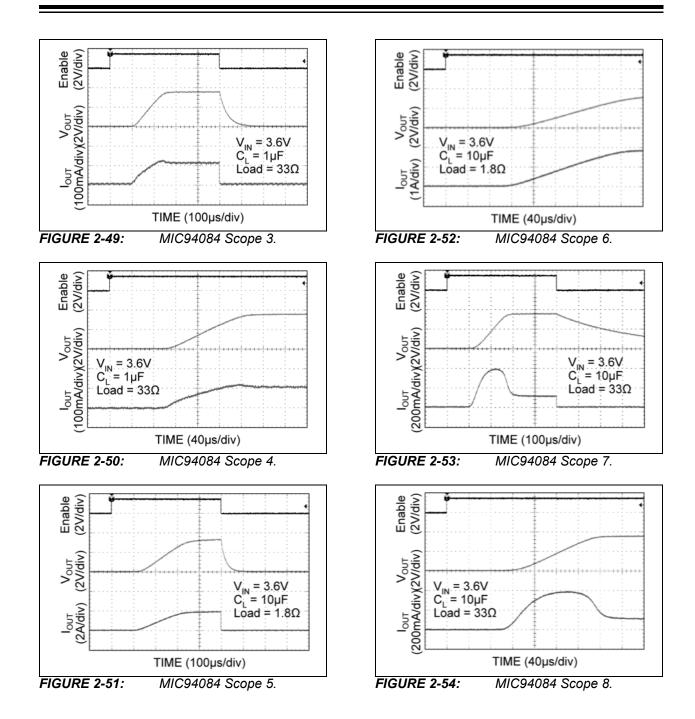
MIC94082 Scope 3.

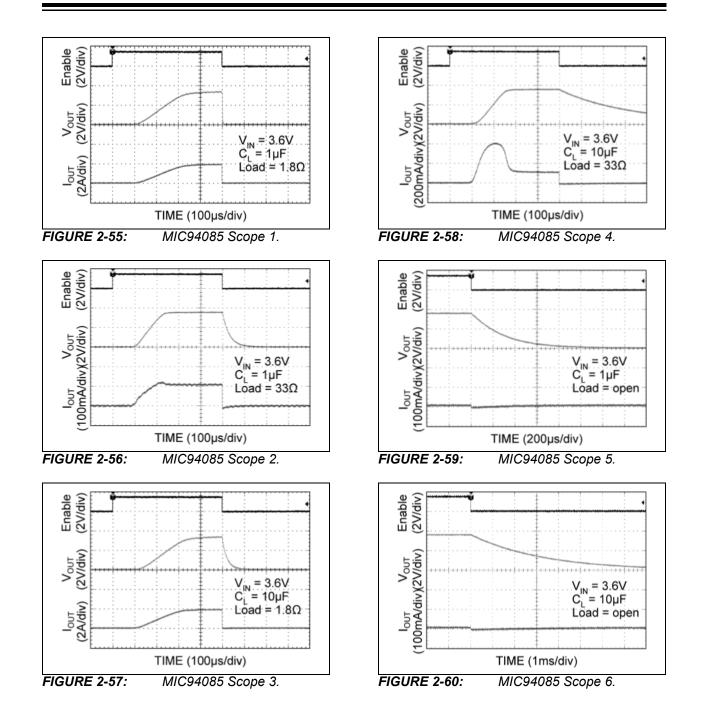
FIGURE 2-36: MIC94082 Scope 6.

TIME (400µs/div)









#### 3.0 PIN DESCRIPTIONS

The descriptions of the pins are listed in Table 3-1.

#### TABLE 3-1: PIN FUNCTION TABLE

Pin Number	Pin Name	Description		
1	V <sub>OUT</sub>	Drain of P-Channel MOSFET.		
2	GND	Ground. Should be connected to electrical ground.		
3	V <sub>IN</sub>	Source of P-Channel MOSFET.		
4	EN	Enable (Input): Active-high CMOS/TTL control input for switch. Internal ~2 M $\Omega$ pull-down resistor. Output will be off if this pin is left floating.		

#### 4.0 APPLICATION INFORMATION

#### 4.1 Power Switch SOA

The safe operating area (SOA) curve represents the boundary of maximum safe operating current and maximum safe operating junction temperature.

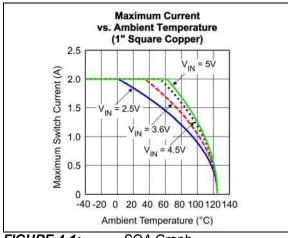


FIGURE 4-1: SOA Graph.

The curves above show the SOA for various  $V_{\text{IN}}$  values mounted on a typical one-layer, 1 square inch copper board.

#### 4.2 **Power Dissipation Considerations**

As with all power switches, the current rating of the switch is limited mostly by the thermal properties of the package and the PCB on which it's mounted. There is a simple Ohm's law type relationship between thermal resistance, power dissipation, and temperature that are analogous to an electrical circuit.

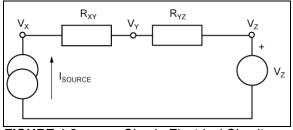


FIGURE 4-2:

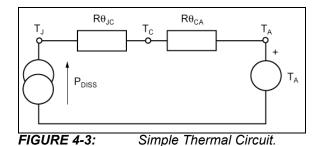
Simple Electrical Circuit.

From this simple circuit, one can calculate V<sub>X</sub> if one knows  $I_{SOURCE}$ , V<sub>Z</sub>, and the resistor values for R<sub>XY</sub> and R<sub>YZ</sub> using Equation 4-1.

**EQUATION 4-1:** 

$$V_X = I_{SOURCE} \times (R_{XY} + R_{YZ}) + V_Z$$

Thermal circuits can be considered using these same rules and can be drawn similarly by replacing current sources with power dissipation (in Watts), resistance with thermal resistance (in  $^{\circ}C/W$ ), and voltage sources with temperature (in  $^{\circ}C$ ).



By replacing the variables in the equation for V<sub>X</sub>, one can find the junction temperature (T<sub>J</sub>) from power dissipation, ambient temperature, and then know thermal resistance of the PCB ( $R\theta_{CA}$ ) and the package ( $R\theta_{JC}$ ).

#### **EQUATION 4-2:**

$$T_{I} = P_{DISS} \times (R\theta_{IC} + R\theta_{CA}) + T_{A}$$

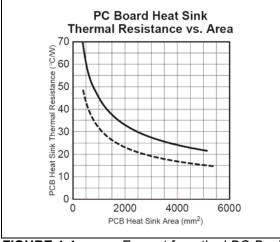
 $P_{DISS}$  is calculated as  $I_{SWITCH}^2 \times R_{SW(MAX)}$ .  $R\theta_{JC}$  is found in the Temperature Specifications section of this data sheet and  $R\theta_{CA}$  (the PCB thermal resistance) values for various PCB copper areas is discussed in Designing with Low Dropout Voltage Regulators.

#### 4.2.1 AN EXAMPLE

A switch is intended to drive a 1A load and is placed on a PCB that has a ground plane area of at least 25 mm by 25 mm (625 mm<sup>2</sup>). The voltage source is a Li-ion battery with a lower operating threshold of 3V and the ambient temperature of the assembly can be up to  $50^{\circ}$ C.

Summary of variables:

- I<sub>SW</sub> = 1A
- V<sub>IN</sub> = 3V to 4.2V
- T<sub>A</sub> = 50°C
- Rθ<sub>JC</sub> = 85°C/W
- $R\theta_{CA} = 53^{\circ}C/W$  (as read from Figure 4-4)





Excerpt from the LDO Book.

#### **EQUATION 4-3:**

$$P_{DISS} = I_{SW}^{2} \times R_{SW(MAX)}$$

The worst case switch resistance ( $R_{SW(MAX)}$ ) at the lowest  $V_{IN}$  of 3V is not available in the data sheet, so the next lowest value of  $V_{IN}$  is used.

 $R_{SW(MAX)}$  at 2.5V is 200 m $\Omega.$ 

An additional consideration is to allow for the maximum junction temperature of 125°C. If this was a calculation for the worst case  $R_{SW(MAX)}$  for 25°C, the actual worst case resistance in this case can be 30% higher (see Figure 2-1). However, 200 m $\Omega$  is the maximum over temperature. Therefore:

#### **EQUATION 4-4:**

$$T_J = 1^2 \times 0.2 \times (85 + 53) + 50 = 78^{\circ}C$$

This is below the maximum of 125°C.

#### 5.0 PACKAGING INFORMATION

#### 5.1 Package Marking Information

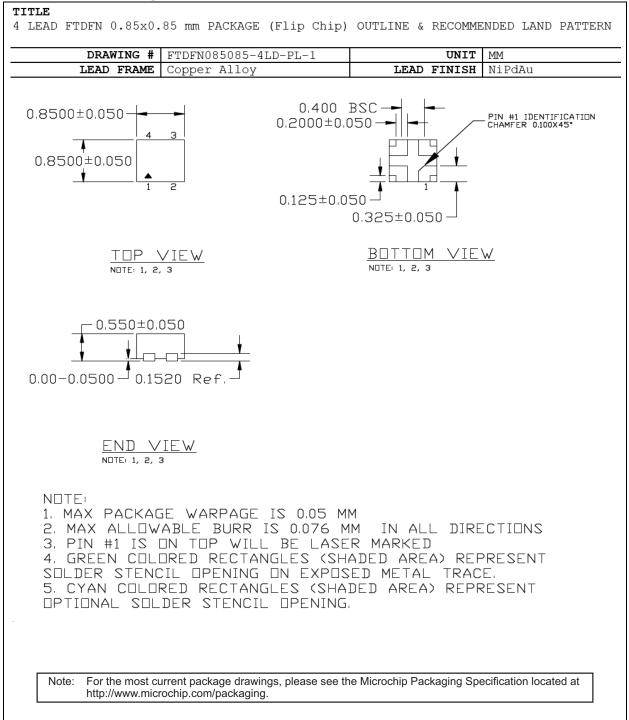


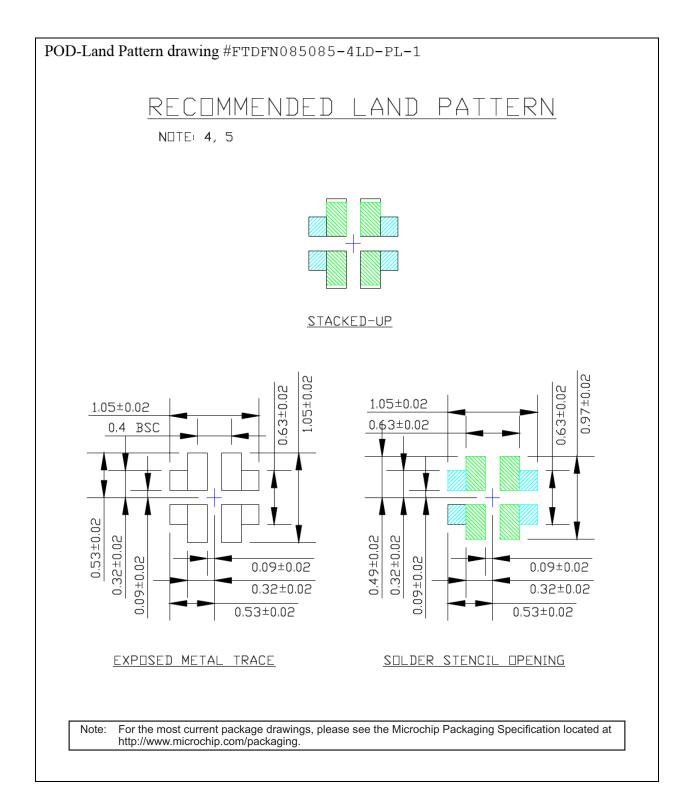
#### TABLE 5-1: MARKING CODES

Part Number	Marking Code	Features
MIC94080YFT-TR	C1	Fast Turn-On
MIC94081YFT-TR	C2	Fast Turn-On, Load Discharge
MIC94082YFT-TR	C5	800 μs Soft-Start
MIC94083YFT-TR	C7	800 µs Soft-Start, Load Discharge
MIC94084YFT-TR	C0	120 µs Soft-Start
MIC94085YFT-TR	1C	120 µs Soft-Start, Load Discharge

Legen	Y YY WW NNN @3 *	Product code or customer-specific information Year code (last digit of calendar year) Year code (last 2 digits of calendar year) Week code (week of January 1 is week '01') Alphanumeric traceability code Pb-free JEDEC <sup>®</sup> designator for Matte Tin (Sn) This package is Pb-free. The Pb-free JEDEC designator (e3) can be found on the outer packaging for this package.
Note:	be carried characters the corpor	nt the full Microchip part number cannot be marked on one line, it will d over to the next line, thus limiting the number of available of or customer-specific information. Package may or may not include ate logo. (_) and/or Overbar ( <sup>-</sup> ) symbol may not be to scale.

#### 4-Lead FTDFN Package Outline & Recommended Land Pattern





NOTES:

#### APPENDIX A: REVISION HISTORY

#### **Revision A (March 2019)**

- Converted Micrel document MIC94080/1/2/3/4/5 to Microchip data sheet template DS20006118A.
- Minor grammatical text changes throughout.

NOTES:

#### **PRODUCT IDENTIFICATION SYSTEM**

To order or obtain information, e.g., on pricing or delivery, contact your local Microchip representative or sales office.

				Example	es:	
Device Part No.	<b>⊻</b> Junction Temp. Range	<b>XX</b> Package	- <u>XX</u> Media Type	,	080YFT-TR: 081YFT-TR:	MIC94080, -40°C to +125°C Temperature Range, 4-Lead FTDFN, 5,000/Reel MIC94081, -40°C to +125°C
Device:	wit   MIC94081: 67   wit   MIC94082: 67   wit   MIC94083: 67   wit   MIC94084: 67   WIC 94084:   67 wit   MIC94084: 67	h Fast Túrn-On mΩ R <sub>DS(ON)</sub> 2A Hig h Fast Turn-On and mΩ R <sub>DS(ON)</sub> 2A Hig h 800 µs Soft-Start mΩ R <sub>DS(ON)</sub> 2A Hig h 800 µs Soft-Start mΩ R <sub>DS(ON)</sub> 2A Hig h 120 µs Soft-Start mΩ R <sub>DS(ON)</sub> 2A Hig	gh-Side Load Switch Joad Discharge Jh-Side Load Switch and Load Switch and Load Discharge Jh-Side Load Switch and Load Discharge	c) MIC94 d) MIC94 e) MIC94	082YFT-TR: 083YFT-TR: 084YFT-TR: 085YFT-TR:	Temperature Range, 4-Lead FTDFN, 5,000/Reel MIC94082, -40°C to +125°C Temperature Range, 4-Lead FTDFN, 5,000/Reel MIC94083, -40°C to +125°C Temperature Range, 4-Lead FTDFN, 5,000/Reel MIC94084, -40°C to +125°C Temperature Range, 4-Lead FTDFN, 5,000/Reel MIC94085, -40°C to +125°C
Junction Temperature Range:	$Y = -40^{\circ}C \text{ to}$	+125°C, RoHS-Cor	npliant			Temperature Range, 4-Lead FTDFN, 5,000/Reel
Package: Media Type:	FT = 4-Lead 0 TR = 5.000/Re	.85 mm x 0.85 mm	FTDFN	Note 1:	catalog part nu used for orderi the device pac	identifier only appears in the mber description. This identifier is ng purposes and is not printed on kage. Check with your Microchip r package availability with the

NOTES:

#### Note the following details of the code protection feature on Microchip devices:

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